20 V, 7.0 A, Low V_{CE(sat)} **NPN Transistor**

ON Semiconductor's e²PowerEdge family of low V_{CE(sat)} transistors are miniature surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

• This is a Pb-Free Device

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	20	Vdc
Collector-Base Voltage	V _{CBO}	20	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	Ι _C	5.0	Adc
Collector Current – Peak	I _{CM}	7.0	А
Electrostatic Discharge	ESD	HBM Class 3B MM Class C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, T _A = 25°C Derate above 25°C	P _D (Note 1)	875 7.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	143	°C/W
Total Device Dissipation, $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D (Note 2)	1.5 11.8	W mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	85	°C/W
Thermal Resistance, Junction-to-Lead #3	$R_{\theta JL}$ (Note 2)	23	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

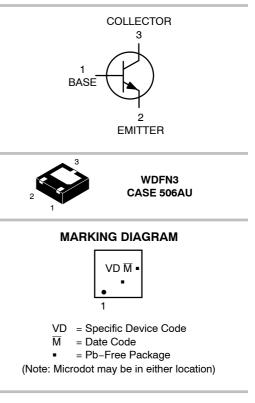
1. FR-4 @ 100 mm², 1 oz copper traces. 2. FR-4 @ 500 mm², 1 oz copper traces.



ON Semiconductor®

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20 VOLTS, 7.0 AMPS NPN LOW V_{CE(sat)} TRANSISTOR EQUIVALENT R_{DS(on)} 31 mΩ



ORDERING INFORMATION

Device	Package	Shipping [†]
NSS20501UW3T2G	WDFN3 (Pb-Free)	3000/ Tape & Reel
NSS20501UW3TBG	WDFN3 (Pb-Free)	3000/ Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS				•	
Collector – Emitter Breakdown Voltage ($I_C = 10 \text{ mAdc}, I_B = 0$)	V _(BR) CEO	20	-	_	Vdc
Collector – Base Breakdown Voltage $(I_C = 0.1 \text{ mAdc}, I_E = 0)$	V _(BR) CBO	20	-	_	Vdc
Emitter – Base Breakdown Voltage $(I_{E} = 0.1 \text{ mAdc}, I_{C} = 0)$	V _{(BR)EBO}	6.0	-	_	Vdc
Collector Cutoff Current ($V_{CB} = 20 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	-	0.1	μAdc
Emitter Cutoff Current (V _{EB} = 6.0 Vdc)	I _{EBO}	_	-	0.1	μAdc
ON CHARACTERISTICS					
$ \begin{array}{l} \text{DC Current Gain (Note 3)} \\ (I_{C} = 10 \text{ mA, } V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 500 \text{ mA, } V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 1.0 \text{ A, } V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 2.0 \text{ A, } V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 3.0 \text{ A, } V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 3.0 \text{ A, } V_{CE} = 2.0 \text{ V}) \end{array} $	h _{FE}	200 200 200 200 180		- - - -	
Collector – Emitter Saturation Voltage (Note 3) ($I_{C} = 0.1 \text{ A}, I_{B} = 0.010 \text{ A}$) ($I_{C} = 1.0 \text{ A}, I_{B} = 0.100 \text{ A}$) ($I_{C} = 1.0 \text{ A}, I_{B} = 0.010 \text{ A}$) ($I_{C} = 2.0 \text{ A}, I_{B} = 0.020 \text{ A}$) ($I_{C} = 3.0 \text{ A}, I_{B} = 0.030 \text{ A}$) ($I_{C} = 4.0 \text{ A}, I_{B} = 0.400 \text{ A}$)	V _{CE(sat)}	- - - - -	0.007 0.031 0.045 0.070 0.120 0.110	0.008 0.040 0.075 0.100 0.135 0.125	V
Base – Emitter Saturation Voltage (Note 3) ($I_c = 1.0 \text{ A}, I_B = 0.01 \text{ A}$)	V _{BE(sat)}	-	0.760	0.900	V
Base – Emitter Turn–on Voltage (Note 3) (I _C = 2.0 A, V _{CE} = 2.0 V)	V _{BE(on)}	-	0.730	0.900	V
Cutoff Frequency (I _C = 100 mA, V _{CE} = 5.0 V, f = 100 MHz)	f _T	150	-	_	MHz
Input Capacitance (V _{EB} = 0.5 V, f = 1.0 MHz)	Cibo	-		650	pF
Output Capacitance (V _{CB} = 3.0 V, f = 1.0 MHz)	Cobo	-		70	pF
SWITCHING CHARACTERISTICS					
Delay (V _{CC} = 15 V, I _C = 750 mA, I _{B1} = 15 mA)	t _d	_	-	90	ns
Rise (V _{CC} = 15 V, I _C = 750 mA, I _{B1} = 15 mA)	t _r	_	-	100	ns
Storage (V _{CC} = 15 V, I _C = 750 mA, I _{B1} = 15 mA)	t _s	-	-	500	ns
Fall (V _{CC} = 15 V, I _C = 750 mA, I _{B1} = 15 mA)	t _f	_	-	100	ns

3. Pulsed Condition: Pulse Width = 300 $\mu sec,$ Duty Cycle \leq 2%.

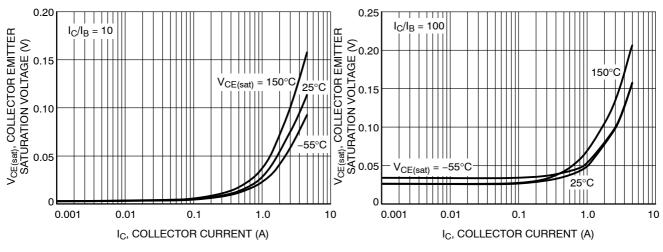
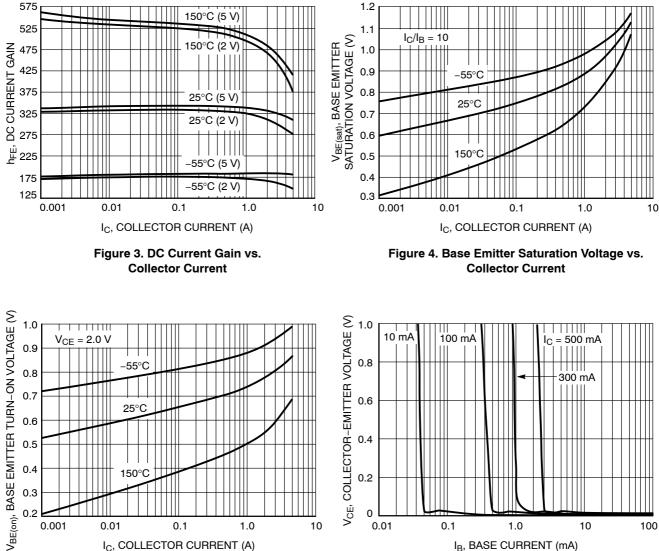




Figure 2. Collector Emitter Saturation Voltage vs. Collector Current



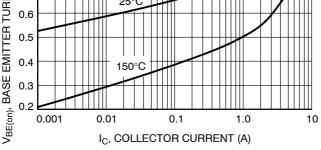


Figure 5. Base Emitter Turn-On Voltage vs. **Collector Current**

Figure 6. Saturation Region

1.0

IB, BASE CURRENT (mA)

10

100

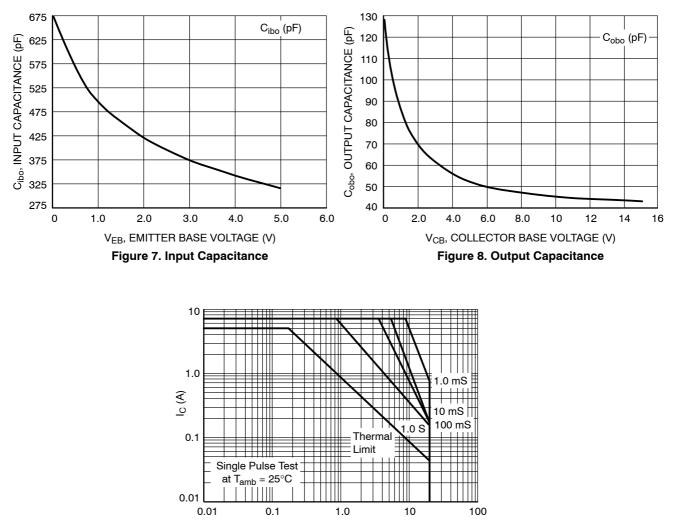
0.4

0.2

0

0.01

0.1

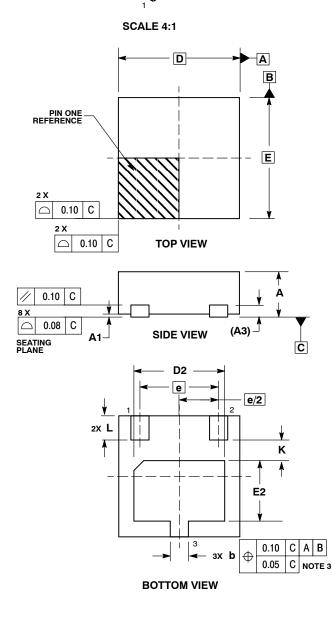


V_{CE} (V_{dc}) Figure 9. Safe Operating Area



WDFN3 2x2, 1.3P CASE 506AU **ISSUE A**

DATE 18 AUG 2016



NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994 . CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS 1.
- 2. 3.
- MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL. 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00		0.05	0.000		0.002
A3		0.20 REF			0.008 REF	
b	0.25	0.30	0.35	0.010	0.012	0.014
D		2.00 BSC			0.079 BSC)
D2	1.40	1.50	1.60	0.055	0.059	0.063
E		2.00 BSC			0.079 BSC	;
E2	0.90	1.00	1.10	0.035	0.039	0.043
е	1.30 BSC				0.051 BSC	;
K	0.35 REF				0.014 REF	
L	0.35	0.40	0.45	0.014	0.016	0.018

GENERIC **MARKING DIAGRAM***



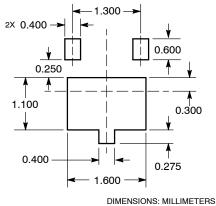
XX = Specific Device Code

М = Date Code

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " .", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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